

V _{DSS}	Drain-Source Voltage		900	V
I _D	Drain Current - Continuous (T _C = 25°C)		5.4	A
	- Continuous (T _C = 100)°C)	3.42	A
I _{DM}	Drain Current - Pulsed	(Note 1)	21.6	A
V _{GSS}	Gate-Source Voltage		± 30	V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	660	mJ
I _{AR}	Avalanche Current	(Note 1)	5.4	A
E _{AR}	Repetitive Avalanche Energy	(Note 1)	15.8	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	4.0	V/ns
P _D	Power Dissipation $(T_A = 25^{\circ}C)^{*}$		3.13	W
	Power Dissipation ($T_C = 25^{\circ}C$)		158	W
	- Derate above 25°C		1.27	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C
TL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C

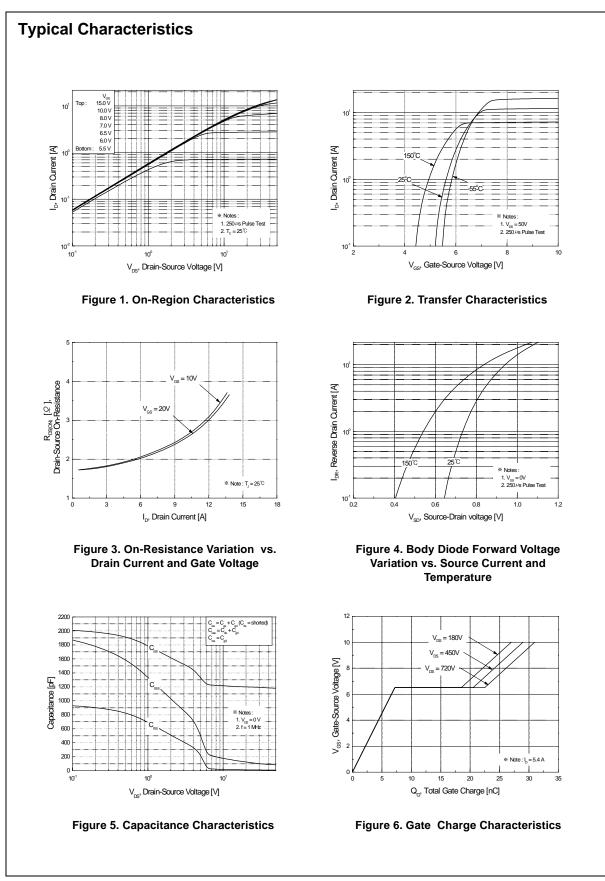
Thermal Characteristics

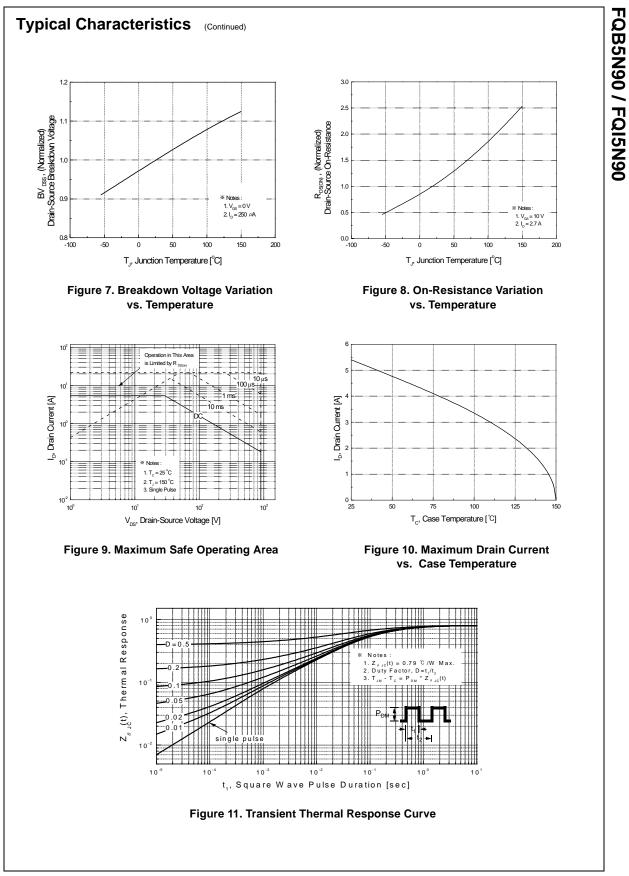
Symbol	Parameter	Тур	Max	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		0.79	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient *		40	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient		62.5	°C/W

Symbol	Parameter	Test Conditions	3	Min	Тур	Max	Units
Off Cha	racteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA		900			V
ΔBV _{DSS} ′ ΔTJ	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}$, Referenced	to 25°C		1.0		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 900 V, V _{GS} = 0 V				10	μA
		V _{DS} = 720 V, T _C = 125°C	;			100	μA
GSSF	Gate-Body Leakage Current, Forward	$V_{GS} = 30 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$				100	nA
GSSR	Gate-Body Leakage Current, Reverse	$V_{GS} = -30 \text{ V}, V_{DS} = 0 \text{ V}$				-100	nA
On Cha	racteristics						
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$		3.0		5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	$V_{GS} = 10V, I_{D} = 2.7 A$			1.8	2.3	Ω
ĴFS	Forward Transconductance	V _{DS} = 50 V, I _D = 2.7 A	(Note 4)		5.6		S
-	ic Characteristics			11			
C _{iss}	Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz			1200	1550	pF
C _{oss}	Output Capacitance				110	145	pF
C _{rss}	Reverse Transfer Capacitance				13	17	pF
Switchi	ng Characteristics						
d(on)	Turn-On Delay Time	V _{DD} = 450 V, I _D = 5.4 A,			28	65	ns
r	Turn-On Rise Time	$R_{G} = 25 \Omega$			65	140	ns
d(off)	Turn-Off Delay Time	NG - 20 32			65	140	ns
f	Turn-Off Fall Time	-	(Note 4, 5)		50	110	ns
כ ^g	Total Gate Charge	V _{DS} = 720 V, I _D = 5.4 A,			31	40	nC
ସୁ _{gs}	Gate-Source Charge	V _{GS} = 10 V			7.2		nC
ე _{gd}	Gate-Drain Charge		(Note 4, 5)		15		nC
Drain-S	ource Diode Characteristics a	nd Maximum Rating	s				
S	Maximum Continuous Drain-Source Did	-				5.4	А
SM	Maximum Pulsed Drain-Source Diode F	Forward Current				21.6	А
V _{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 5.4 A$				1.4	V
rr	Reverse Recovery Time	$V_{GS} = 0 V, I_{S} = 5.4 A,$			610		ns
Q _{rr}	Reverse Recovery Charge	dI _F / dt = 100 A/µs	(Note 4)		5.26		μC
L = 43mH, I _µ I _{SD} \leq 5.4A, Pulse Test :	ating : Pulse width limited by maximum junction tempe $_{LS} = 5.4A$, $V_{DD} = 50V$, $R_G = 25 \Omega$, Starting $T_J = 25^{\circ}C$ di/dt $\leq 200A/\mu s$, $V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^{\circ}C$ Pulse width $\leq 300 \mu s$, Duty cycle $\leq 2\%$ dependent of operating temperature	rature					

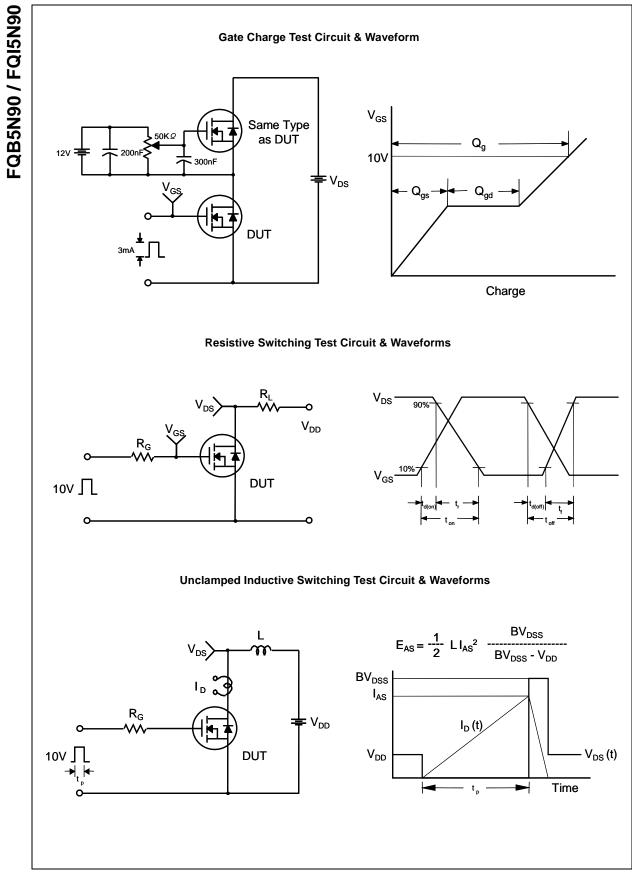
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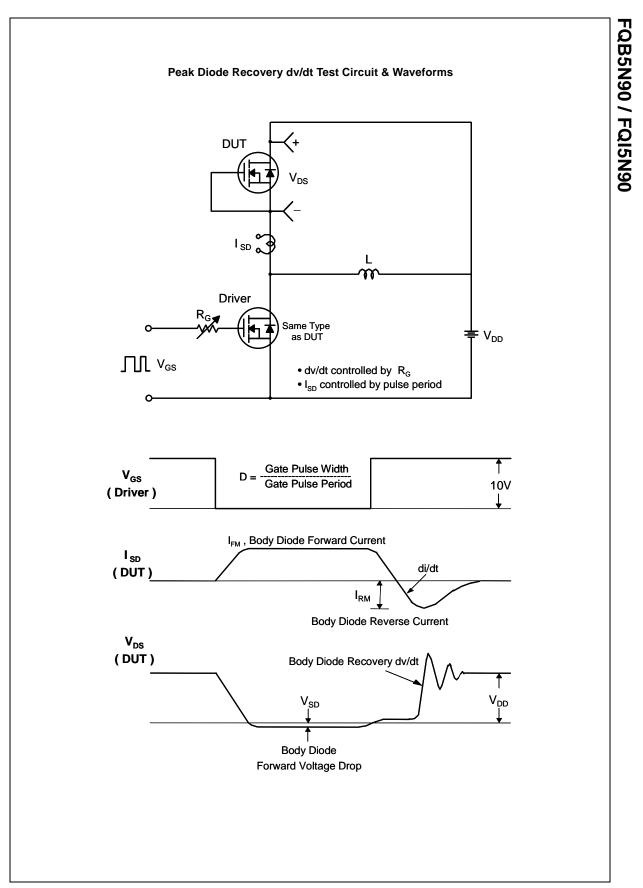




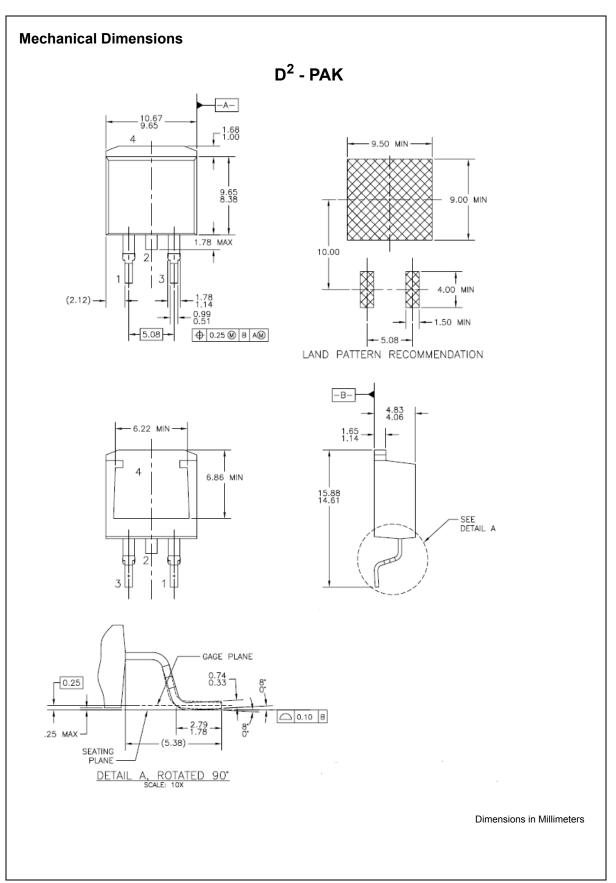
Rev. A1, Oct 2008

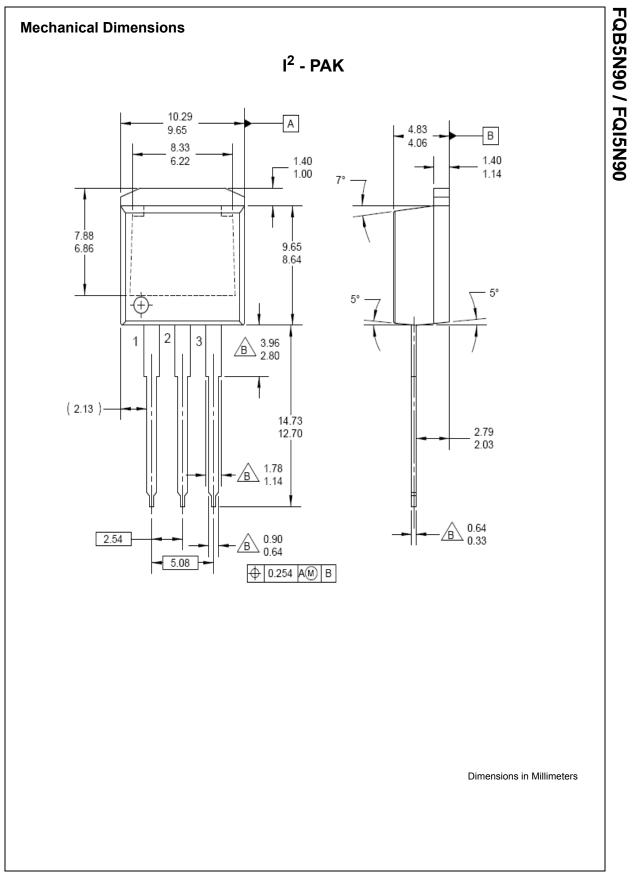


Rev. A1, Oct 2008



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